



600V 16A N-Channel Enhancement Mode Power MOSFET

General Description

BXP16N60 is Bridgelux high voltage MOSFET family based on advanced planar DMOS technology. This advanced MOSFET family has optimized on-state resistance, and also provides superior switching performance and higher avalanche energy strength. This device family is suitable for high efficiency switch mode power supplies.

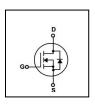
FEATURES

- RDSON \leq 0.5 Ω @Vgs=10V, Id=8A
- Excellent RDS(ON) and Low Gate Charge

Version: 1.1

- · Fast switching capability
- · Lead free product is acquired

SYMBOL







TO-220

TO-220F

ASSEMBLY MESSAGE

| Product Name | Package | Packaging |
|--------------|---------|-----------|
| BXP16N60P | TO-220 | Tube |
| BXP16N60F | TO-220F | Tube |

ABSOLUTE MAXIMUM RATINGS (T_C=25°C unless otherwise noted)

| Parameter | | Cumbal | Rating | | I I m i 4 |
|---------------------------------------|-------------------------------------|------------------|------------|-----------|-----------|
| | | Symbol | BXP16N60P | BXP16N60F | Unit |
| Drain-Source Voltage | | V _{DSS} | 600 | | V |
| Dunin Comment | Continuous (T _C = 25°C) | | 16 | | Α |
| Drain Current | Continuous (T _C = 100°C) | I _D | 11 | | Α |
| Drain Current | Pulsed (Note1) | I _{DM} | 64 | | Α |
| Gate-Source Voltage | | V _{GSS} | ±30 | | V |
| Avalanche Energy Single Pulse (Note2) | | E _{AS} | 975 | | mJ |
| Avalanche Current (Note1) | | I AR | 16 | | А |
| Peak Diode Recovery dv/dt (Note3) | | dv/dt | 5 | | V/ns |
| Power Dissipation (Note | T _C =25°C | Ь | 190 | 42.8 | W |
| 2) | Derate above 25°C | - P _D | 1.5 | 0.34 | W/°C |
| Maximum Junction Temperature | | TJ | 150 | | °C |
| Storage Temperature Range | | TstG | -55 to 150 | | °C |

Note:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L=7.6mH, I_{AS} =16.0A, V_{DD} =50V, RG=25 Ω , Starting TJ = 25°C
- 3. $I_{SD} \le 16.0 A$, di/dt $\le 300 A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting TJ = 25°C



THERMAL CHARACTERISTICS

| Doromotor | Symbol | Ma | 11:4:4 | |
|---|------------------|-----------|-----------|--------|
| Parameter | | BXP16N60P | BXP16N60F | Unit |
| Thermal Resistance, Junction-to-Case | R _{θJC} | 0.66 | 2.92 | °C / W |
| Thermal Resistance, Junction-to-Ambient | R _{θJA} | 62.5 | 62.5 | °C / W |

ELECTRICAL CHARACTERISTICS (T_J=25°C,unless otherwise Noted)

| Parameter | Symbol | Test Condition | Min. | Тур. | Max. | Unit |
|------------------------------------|---------------------|------------------------------|------|------|------|------|
| OFF CHARACTERISTICS | | , | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | VGS=0V, ID=250µA | 600 | | | V |
| Zero Gate Voltage Drain Current | I _{DSS} | VDS=600V, VGS=0V | | | 1 | uA |
| | | VDS=480V, TC = 125°C | | | 100 | uA |
| Gate-Body Leakage Current, Forward | I _{GSS} | VGS=30V | | | 100 | nA |
| Gate-Body Leakage Current, Reverse | | VGS=-30V | | | -100 | nA |
| Breakdown Voltage Temperature | △BVDSS/ | ID 050A | 0.05 | 0.65 | | V/°C |
| Coefficient | △TJ | ID = 250 μA | | 0.65 | | |
| ON CHARACTERISTICS | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | VDS=VGS, ID=250μA | 2 | | 4 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | VGS=10V, ID=8A | | 0.41 | 0.5 | Ω |
| Forward Transconductance (Note4) | g FS | VDS = 50V, ID=8A | | 10 | | S |
| DYNAMIC PARAMETERS | | | | | | |
| Input Capacitance | C _{ISS} | 1/20 05// 1/00 01/ | | 2520 | | pF |
| Output Capacitance | Coss | VDS=25V, VGS=0V, f=1.0MHz | | 215 | | pF |
| Reverse Transfer Capacitance | Crss | | | 11 | | pF |
| SWITCHING PARAMETERS | | | | | | |
| Turn-ON Delay Time | t _{D(ON)} | \/DD 000\/ \ID 404 \/00 | | 30 | | ns |
| Turn-ON Rise Time | t _R | VDD=300V, ID=16A, VGS | | 46 | | ns |
| Turn-OFF Delay Time | t _{D(OFF)} | = 10V ,RG=10Ω (Note4,5) | | 75 | | ns |
| Turn-OFF Fall-Time | t⊧ | (110(64,5) | | 49 | | ns |
| Total Gate Charge(Note5) | Q_{G} | VDS =480V, VGS =10V, ID | | 49.5 | | nC |
| Gate Source Charge | Q _{GS} | =16A | | 12 | | nC |
| Gate Drain Charge | Q_{GD} | (Note4,5) | | 19.6 | | nC |
| SOURCE- DRAIN DIODE RATINGS | AND CHARA | ACTERISTICS | | | | |
| Drain-Source Diode Forward Voltage | V _{SD} | IS=16A, VGS=0V | | | 1.4 | V |
| Diode Continuous Forward Current | Is | | | | 16 | Α |
| Pulsed Drain-Source Current | I _{SM} | | | | 64 | Α |
| Reverse Recovery Time | t _{RR} | VGS = 0 V, ISD = 16A | | 515 | | ns |
| Reverse Recovery Charge | Q _{RR} | di/dt=100 A/µs (Note4,5) | | 5.58 | | uC |

Note: 4. Pulse Test : Pulse width ≤ 300µs, Duty cycle ≤ 2%

5. Essentially independent of operating temperature



0.48

0.47 0.46 0.45

0.44

0.43

0.41

Rds(on), Drain-to-Source Resistance(Ω)

C.Capacitance(pF)

PULSED TEST T_j = 25°C

TYPICAL CHARACTERISTICS

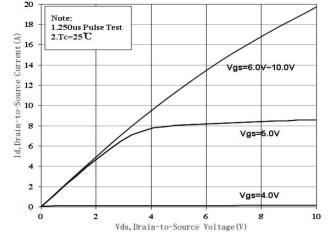
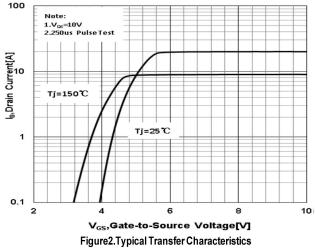


Figure 1.Typical Output Characteristics

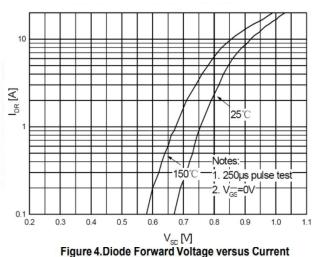
 $V_{GS} = 10V$

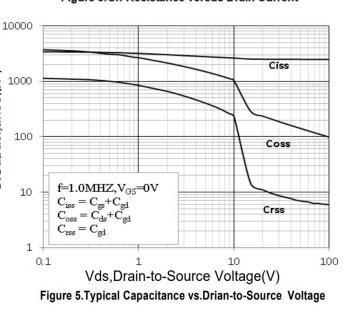


12 14 16

Id, Drain Current(A)
Figure 3.On-Resistance versus Drain Current

10





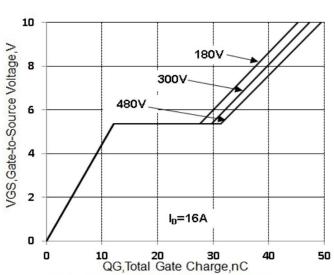


Figure 6. Typical Gate Charge vs. Vgs

TYPICAL CHARACTERISTICS(Cont.)

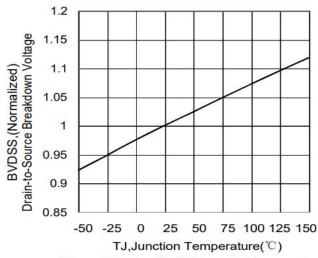


Figure 7.Bvdss Variation with Temperature

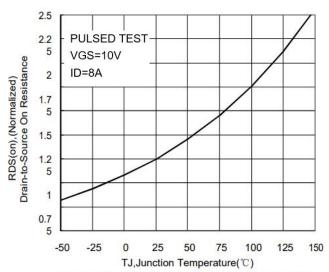


Figure 8.On-Resistance Variation with Temperature

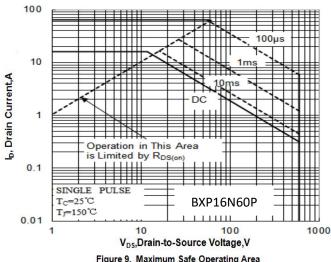


Figure 9. Maximum Safe Operating Area

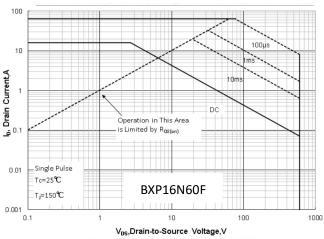


Figure 9. Maximum Safe Operating Area

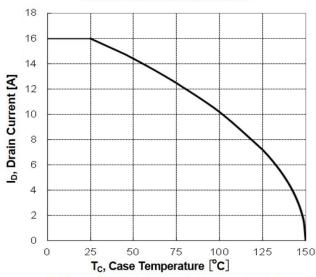
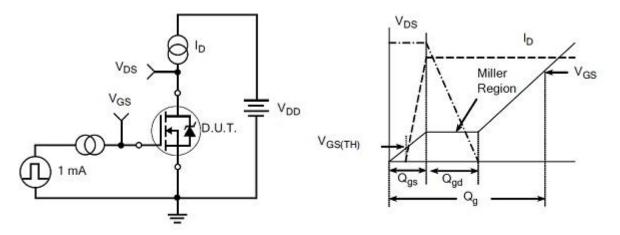


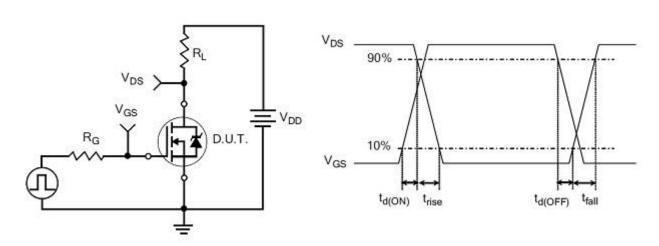
Figure 10. Maximum Continuous Drain **Current vs Case Temperature**

TEST CIRCUITS AND WAVEFORMS



Gate Charge Test Circuit

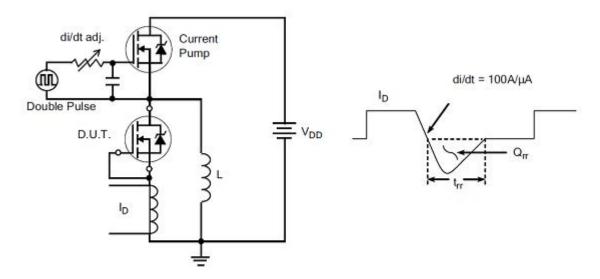
Gate Charge Waveform



Resistive Switching Test Circuit

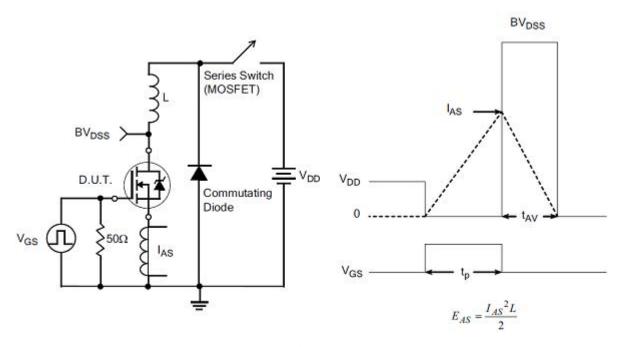
Resistive Switching Waveforms

TEST CIRCUITS AND WAVEFORMS(Cont.)



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms





Revision history

Document revision history

| Date | Revision | Changes |
|-------------|----------|------------------|
| 16-Aug-2021 | 1.0 | First release |
| 8-Jan-2022 | 1.1 | Update parameter |
| | | |
| | | |



Bridgelux WuXi R&D CO.,LTD

Halogen Free
BXP16N60

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